

**240V P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET**

**Features**

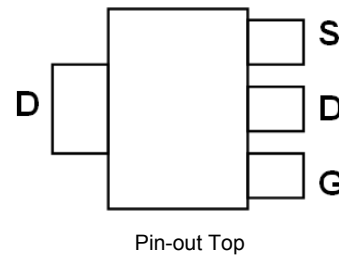
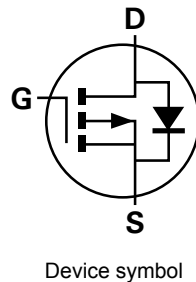
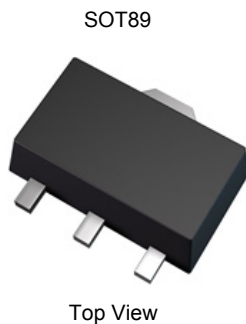
- $BV_{DSS} > -240V$
- $R_{DS(on)} \leq 8.8\Omega @ V_{GS} = -3.5V$
- Low threshold and Fast switching
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

**Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish <sup>③</sup>
- Weight: 0.052 grams (approximate)

**Application**

- Electronic hook switches
- Telecoms and Battery powered equipment

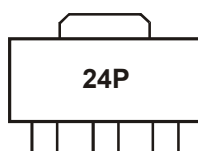


**Ordering Information** (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVP4424ZTA	AEC-Q101	24P	7	12	1,000
ZVP4424ZQTA	Automotive	24P	7	12	1,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
  3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
  5. For packaging details, go to our website at <http://www.diodes.com>.

**Marking Information**



24P = Product type Marking Code

**Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

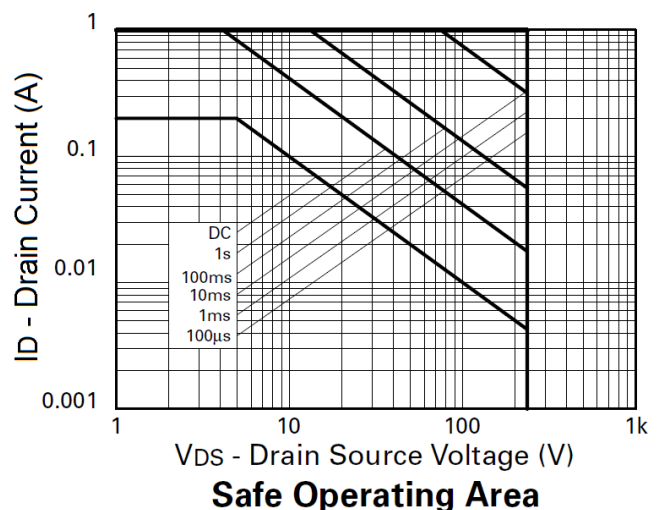
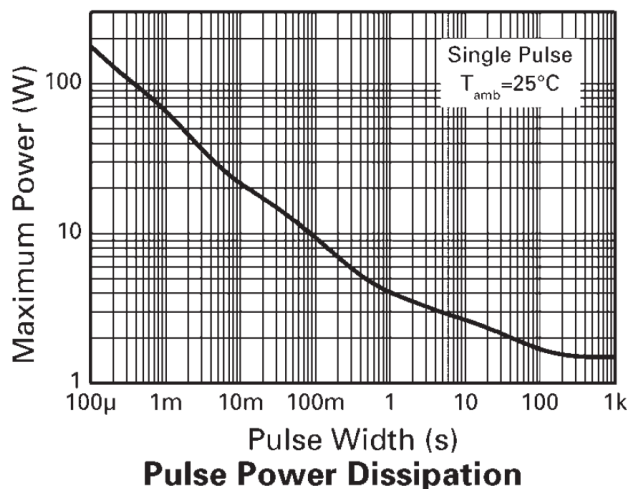
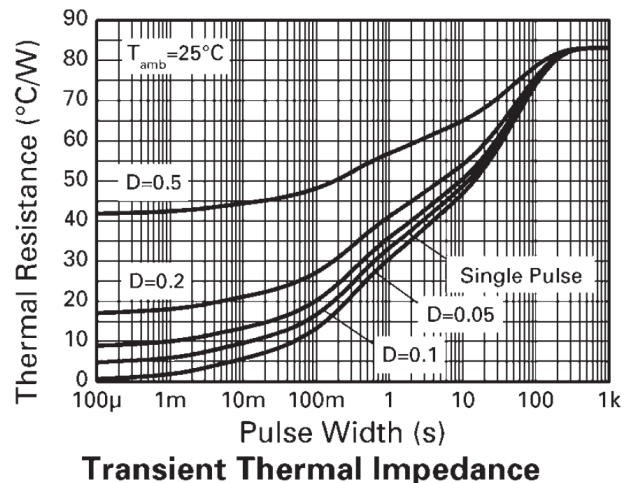
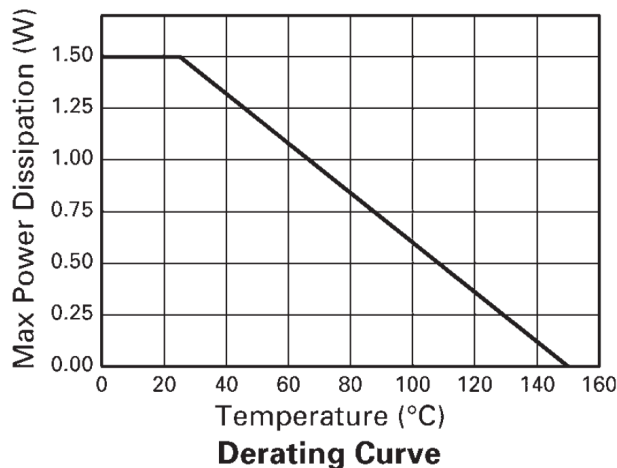
Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	-240	V
Gate-Source Voltage	$V_{GSS}$	$\pm 40$	V
Continuous Drain Current	$I_D$	-200	mA
Pulsed Drain Current (Note 8)	$I_{DM}$	-1.0	A

**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	$P_D$	1.5	W
		2.6	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	83.3	$^\circ\text{C/W}$
		47.4	$^\circ\text{C/W}$
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	3.64	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
6. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
  7. For a device surface mounted on FR4 PCB measured at  $t \leq 10$  sec.
  8. Repetitive rating - 25mm x 25mm FR4 PCB,  $D = 0.02$ , pulse width 300 $\mu\text{s}$  – pulse width limited by maximum junction temperature.
  9. Thermal resistance from junction to solder-point (at the end of the drain lead).

**Thermal Characteristics**

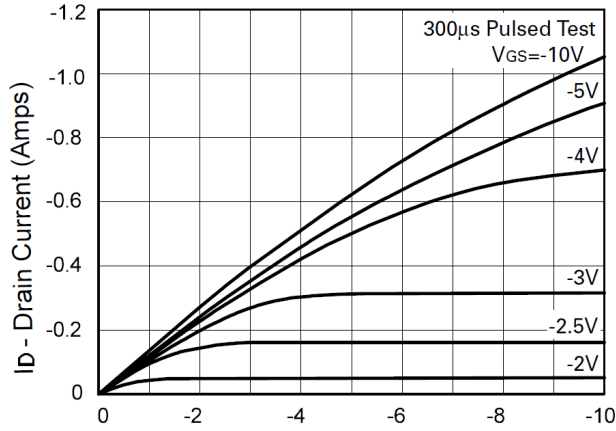


**Electrical Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

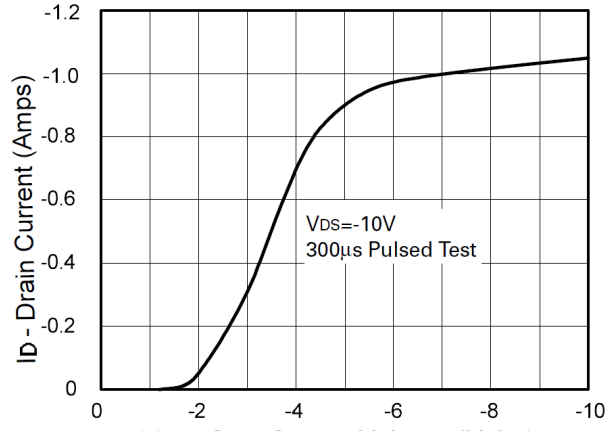
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	-240	—	—	V	$I_D = -1\text{mA}, V_{GS} = 0\text{V}$
Zero Gate Voltage Drain Current	$I_{DSS}$	—	—	-10 -100	$\mu\text{A}$ $\mu\text{A}$	$V_{DS} = -240\text{V}, V_{GS} = 0\text{V}$ $V_{DS} = -190\text{V}, V_{GS} = 0\text{V}, T_A = +125^\circ\text{C}$
Gate-Source Leakage	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{GS} = \pm 40\text{V}, V_{DS} = 0\text{V}$
<b>ON CHARACTERISTICS</b>						
On state Drain Current (Note 10)	$I_{D(on)}$	-0.75	-1.0	—	A	$V_{DS} = -10\text{V}, V_{GS} = -10\text{V}$
Gate Threshold Voltage	$V_{GS(th)}$	-0.7	-1.4	-2.0	V	$I_D = -1\text{mA}, V_{DS} = V_{GS}$
Static Drain-Source On-Resistance (Note 10)	$R_{DS(on)}$	—	7.1 8.8	9 11	$\Omega$	$V_{GS} = -10\text{V}, I_D = -200\text{mA}$ $V_{GS} = -3.5\text{V}, I_D = -100\text{mA}$
Forward Transconductance (Notes 10 & 12)	$g_{fs}$	125	—	—	mS	$V_{DS} = -10\text{V}, I_D = -200\text{mA}$
<b>DYNAMIC CHARACTERISTICS (Note 12)</b>						
Input Capacitance	$C_{iss}$	—	100	200	pF	$V_{DS} = -25\text{V}, V_{GS} = 0\text{V}$ $f = 1.0\text{MHz}$
Output Capacitance	$C_{oss}$	—	18	25		
Reverse Transfer Capacitance	$C_{rss}$	—	5	15		
Turn-On Delay Time (Note 11)	$t_{d(on)}$	—	8	15	ns	$V_{DD} = -50\text{V}, I_D = -250\text{mA}$ $V_{GEN} = -10\text{V}$
Rise Time (Note 11)	$t_r$	—	8	15		
Turn-Off Delay Time (Note 11)	$t_{d(off)}$	—	26	40		
Fall Time (Note 11)	$t_f$	—	20	30		

- Notes:
- 10. Measured under pulsed conditions. Pulse width = 300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$ .
  - 11. Switching characteristics are independent of operating junction temperature.
  - 12. For design aid only, not subject to production testing.

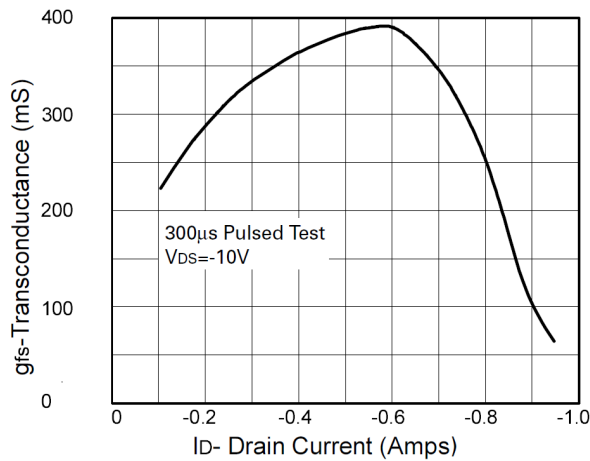
**Typical Characteristics**



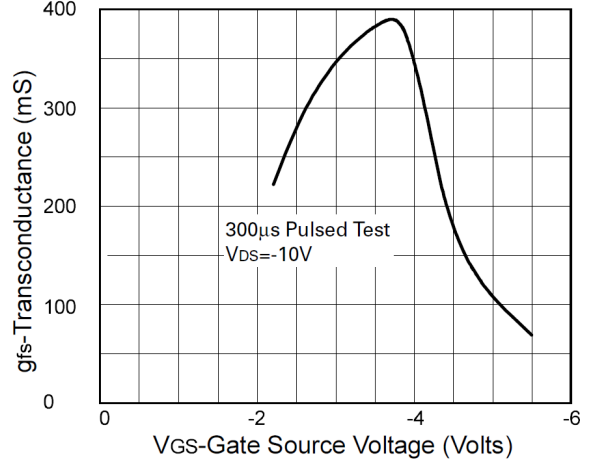
**Saturation Characteristics**



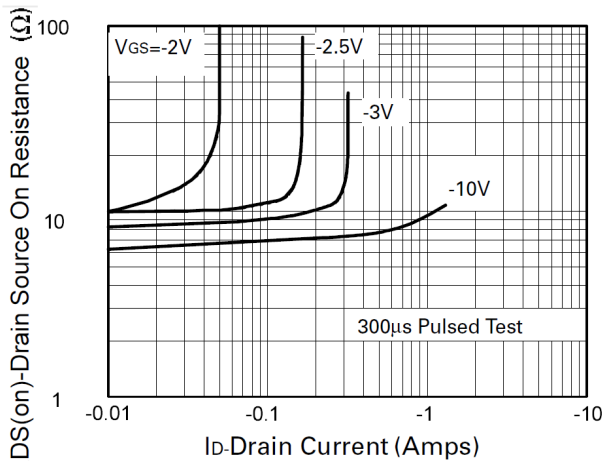
**Transfer Characteristics**



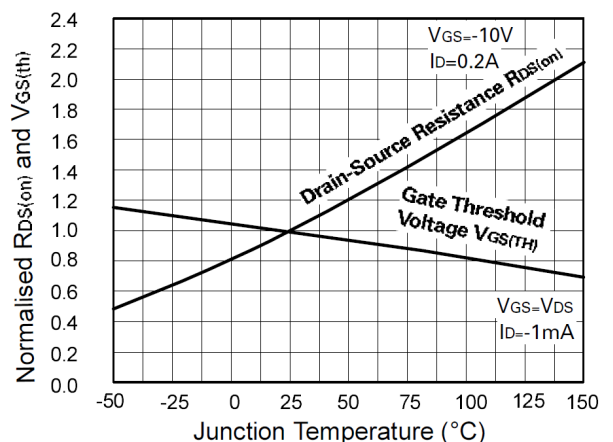
**Transconductance v drain current**



**Transconductance v gate-source voltage**



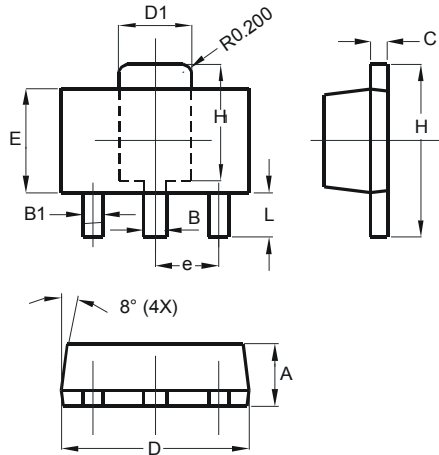
**On-resistance vs Drain Current**



**Normalised RDS(on) and VGS(th) vs Temperature**

## Package Outline Dimensions

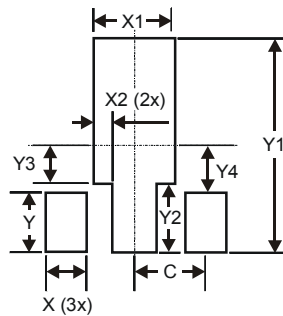
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT89		
Dim	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.44
D	4.40	4.60
D1	1.62	1.83
E	2.29	2.60
e	1.50 Typ	
H	3.94	4.25
H1	2.63	2.93
L	0.89	1.20
All Dimensions in mm		

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2012, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)